7-SEGMEN

12



Data sheet acquired from Harris Semiconductor SCHS072B – Revised July 2003

CMOS BCD-to-7-Segment Latch Decoder Drivers

High-Voltage Types (20-Volt Rating)





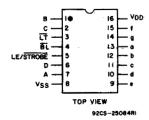
220 - 25087

CD4511B types are BCD-to-7-segment latch decoder drivers constructed with CMOS logic and n-p-n bipolar transistor output devices on a single monolithic structure. These devices combine the low quiescent power dissipation and high noise immunity features of RCA CMOS with n-p-n bipolar output transistors capable of sourcing up to 25 mA. This capability allows the CD4511B types to drive LED's and other displays directly.

Lamp Test (LT), Blanking (BL), and Latch Enable or Strobe inputs are provided to test the display, shut off or intensity-modulate it, and store or strobe a BCD code, respectively. Several different signals may be multiplexed and displayed when external multiplexing circuitry is used.

The CD4511B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

These devices are similar to the type MC14511.



CD4511B TERMINAL ASSIGNMENT

Features:

- High-output-sourcing capability up to 25 mA
- Input latches for BCD Code storage
- Lamp Test and Blanking capability
- 7-segment outputs blanked for BCD input codes > 1001
- 100% tested for quiescent current at 20 V
- Max. input current of 1 μA at 18 V, over full package-temperature range, 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings

Applications:

Driving common-cathode LED displays

V_{SS}=8 V_{DD}=16

FUNCTIONAL DIAGRAM

- Multiplexing with common-cathode LED displays
- Driving incandescent displays

CD4511B Types

■ Driving low-voltage fluorescent displays

MAXIMUM RATINGS, Absolute-Maximum Values: DC SUPPLY-VOLTAGE RANGE, (VDD) Voltages referenced to VSS Terminal) -0.5V to +20V INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to VDD +0.5V DC INPUT CURRENT, ANY ONE INPUT ±10mA POWER DISSIPATION PER PACKAGE (PD): For TA = -55°C to +100°C For TA = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW OPERATING-TEMPERATURE RANGE (Tatg) STORAGE TEMPERATURE (Tatg) At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

OPERATING CONDITIONS AT TA = 25°C Unless Otherwise Specified

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

Characteristic	V _{DD}	Min.	Max.	Units	
Supply Voltage Range (T _A): (Full Package-Temperature Range)		3	18		
Set-Up Time (t _S)	5	150	-	ns	
	10	70	_	ns	
	15	40		ns	
Hold Time (t _H)	5	0	_	ns	
	10	0	_	ns	
	15	0	-	ns	
	5	400	_	ns	
Strobe Pulse Width (t _W)	10	160	_	ns	
	15	100	_	ns	

CD4511B Types

STATIC ELECTRICAL CHARACTERISTICS

	TEST CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)									
		V ₀ (V)	V _{IN} (V)		LIMITS AT INDICATED TEMPERATURES (-C)								
CHARACTERISTIC	ІОН			VDD		[+25		Units	
	(mA)			(V)	-55 -4 0	+85	+125	Min.	Тур.	Max.			
Quiescent Device	_			5	5	5	150	150	_	0.04	5		
Current: I _{DD}			_	10	10	10	300	300		0.04	10	μΑ	
	_		1	15	20	20	600	600	_	0.04	20] "^	
		_	-	20	100	100	3000	3000	-	0.08	100		
Output Voltage:													
	-		0,5	5			0.05		· -	0	0.05		
Low Level VOL			0,10	10			0.05		-	0	0.05	· V	
Max.			0,15	15			0.05	,		0	0.05	•	
	<u> </u>	=	0,5	5	4	4	4.2	4.2	4.1	4.55	L <u>-</u>		
High-Level V _{OH}	ļ	-	0,10	10	9	9	9.2	9.2	9.1	9.55		V	
Min.	-	-	0.15	15	14	14	14.2.	14.2	14.1	14.55	-	L	
Input Low	-	0.5,3.8		5	1.5					_	1.5		
Voltage, VIL	-	1,8.8	-	10			3		-	_	3	V	
Max.	-	1.5,13.8		15	4				-		4		
Input High	-	0.5,3,8		5	3.5				3.5	-		v	
Voltage, VIH	_	1,8.8		10					7				
Min.	-	1.5,13.8		15			11	11			1 *		
	0			A	4.0	4.0	4.20	4.20	4.10	4.55			
	5	_			4.0	4.0	4.20	4.20	4.10	4.25			
	10	-		 5	3.80	3.80	3.90	3.90	3.90	4.10			
	15		_	ĭ	9.00	3.00	3.50	3.50	3.90	3.95	-	٧	
	20				3.55	3.55	3.30	3.30	3.40	3.75			
ļ	25				3.40	3.40			3.10	3.55			
	0	—		+									
Output Drive	5			T	9.0	9.0	9.20	9.20	9.10	9.55 9.25			
•	10	·			8.85	8.85	9.00	9.00	9.00	9.25			
Voltage: High Level V _{OH} Min.	15	-	_	10	- 0.00	8.85	9.00	9.00	9.00	9.15		V	
	20				8.70	8.70	8.40	8.40	8.60	8.90			
	25	-	-		8.60	8.60	-	-	8.30	8.75	· <u>-</u>		
	0			4	14.0	14.0	14.20	14.20	14.10	14.55			
	5							-		14.30			
	10			15	13.90	13.90	14.0	14.0	14.0	14.20	-	V	
	15				40.75	-	-	-		14.10			
	20 25		-		13.75	13.75	13.50	13.50	13.70	13.95	-		
	25				13.65	13.65			13.50	13.80		<u> </u>	
_													
Output Low (Sink) Current,	_	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	_		
OL		0.5	0,10	10	1.6	1.5	1.1	0.36	1.3	2.6		mA	
OL Min.	_	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8			
Input	_		0,18	18	±0.1	±0.1	±1	±1	- J. T	±10-5		μΑ	
Current, IIN Max.													

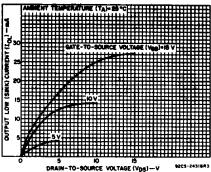


Fig. 1 — Typical output low (sink) current characteristics.

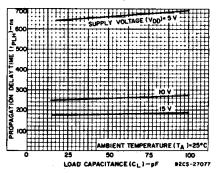


Fig. 2 — Typical data-to-output, low-to-high-level propagation dalay time as a function of load capacitance.

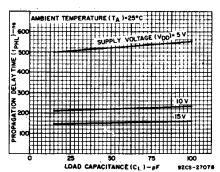


Fig. 3 — Typical data-to-output, high-to-low-level propagation delay time as a function of load capacitance.

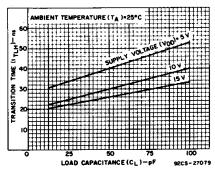


Fig. 4 — Typical low-to-high-level transition time as a function of load capacitance.

CD4511B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$, Input t_r , $t_f = 20$ ns, C_L = 50 pF, R_L = 200 k Ω

CHARACTERISTIC	Test Conditions	A	UNITS			
X	V _{DD} Volts	Min.	Тур.	Max.	Olviis	
Propagation Delay Time:	5	_	520	1040		
(Data)	10	l	210	420	ns	
High-to-Low Level, tpHL	15	-	150	300		
	5	-	660	1320		
Low-to-High Level, tpLH	10	i –	260	520	ns	
	15		180	360	<u>. </u>	
Propagation Delay Time:	5	_	350	700		
(BL)	10	-	175	350	ns	
High-to-Low Level, tpHL	15	_	125	250		
	5		400	800		
» Low-to-High Level, tpLH	10	_	175	350	ns	
	15		150	300		
Propagation Delay Time:	5	_	250	500		
(LT)	10	-	125	250	ns	
High-to-Low Level, tpHL	15	_	85	170		
·	5		150	300		
Low-to-High Level, tpLH	10	_	75	150	ns	
	15	_	50	100		
Transition Time:	. 5	_	40	80		
	10	-	30	60	пѕ	
Low-to-High Level, tTLH	15	_	25	50		
	5	-	125	310		
	10	_	75	185	ns	
High-to-Low Level, tTHL	15	_	65	160		
A4:-:	5	150	75	_		
Minimum Set-Up Time, t _S	10	70	35	-	ns	
	15	40	20	_		
	5	0	-75	_		
Minimum Hold Time, tH	10	0	-35	_	ns	
	15	0	-20	_		
S	5	400	200	_		
Strobe Pulse Width, t _W	10	160	80	. —	ns	
	15	100	50			
Input Capacitance, CIN			5	7.5	pF	

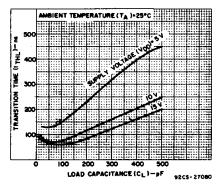


Fig. 5 - Typical high-to-low transition time as a function of load capacitance.

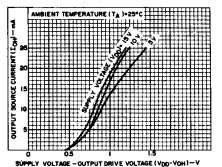


Fig. 6 - Typical voltage drop (V_{DD} to output) vs. output source current as a function of supply.

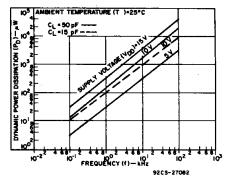
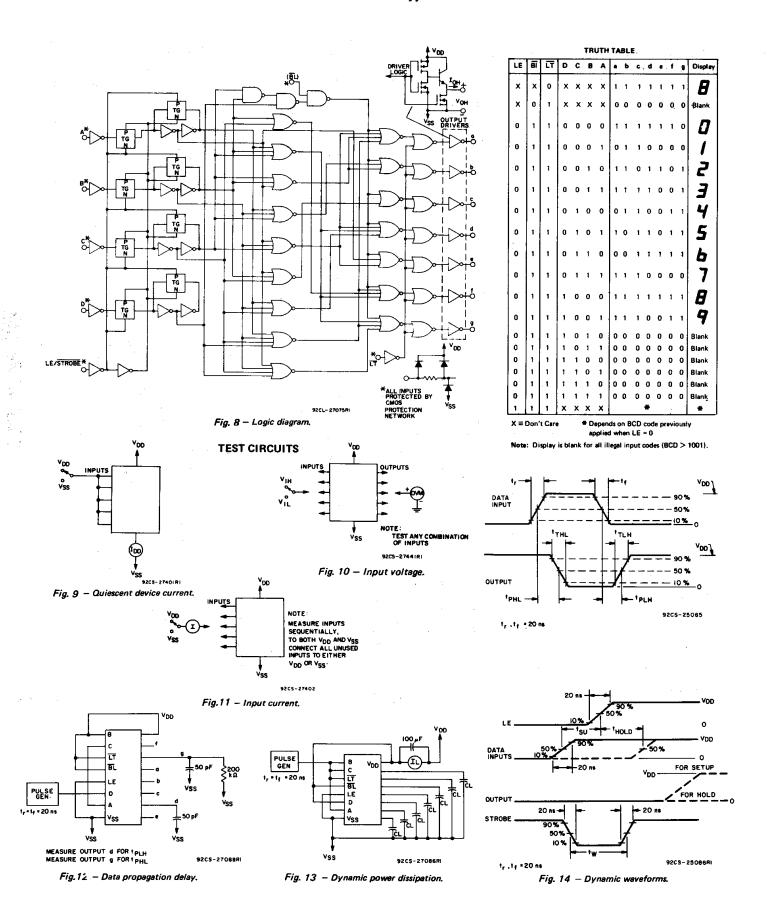
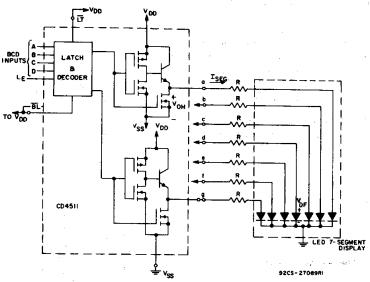


Fig. 7 - Typical dynamic power dissipation characteristics.

CD4511B Types



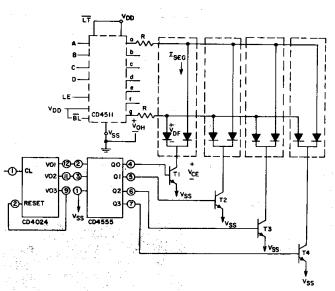
APPLICATIONS Interfacing with Various Displays



Duty Cycle = 100%

ISEG = IDIODEAVG. = 20 mA at Luminous Intensity/Segment = 250 microcandles

Fig. 15 - Driving common-cathode 7-segment LED displays (example Hewlet-Packard 5082-7740).



Multiplexing Scheme Showing 2 of 7 Segments Connected

Transistors T₁-T₄ (RCA-2N3053 or 2N2102) have I_C Max.rating >7xI_{SEG}

Duty Cycle = 25% ${}^{I}SEG = {}^{I}DIODE_{AVG}{}^{J} \times 4$ $R = \frac{(V_{OH} - V_{DF} - V_{CE})}{{}^{I}SEG}$

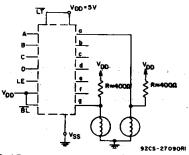
All unused inputs on CD4555 are connected to V_{DD} or V_{SS} .

Fig. 18 — Multiplexing with common-cathode 7-segment LED displays (example Hewlet-Packard 5082-7404 4 character display or 4 discrete Monosanto Man 3 displays).

A medium-brightness intensity display can be obtained with low-voltage fluorescent displays such as the Tung-Sol Digivac S/G** Series.

**Trademark Tung-Sol Division Wagner Electric Co.

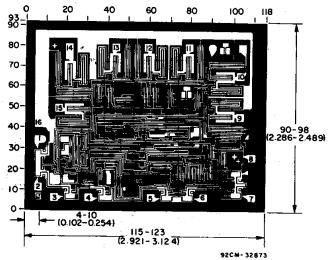
Fig. 16 — Driving low-voltage fluorescent displays.



2 of 7 Segments Shown Connected

Resistors R from V_{DD} to each 7-segment driver output are chosen to keep all Numitron segments slightly on and warm.

Fig. 17 — Driving incandescent displays (RCA Numitron DR2000 series displays).



Dimensions and pad layout for CD45118 chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).